

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	32	V
Collector-Base Voltage	V_{CBO}	32	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Collector Current — Continuous	I_C	100	mA

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board,* $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225	mW
		1.8	mW/°C
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate,** $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300	mW
		2.4	mW/°C
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	°C

*FR-5 = 1.0 x 0.75 x 0.062 in.

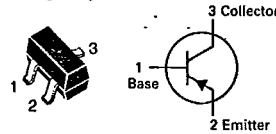
**Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

DEVICE MARKING

BCW61AL = BA; BCW61BL = BB; BCW61CL = BC; BCW61DL = BD

MOTOROLA SC XSTRS/R F

BCW61AL, BL, CL, DL T-27-01

CASE 318-03, STYLE 6
SOT-23 (TO-236AB)GENERAL PURPOSE
TRANSISTORS
PNP SILICON

Refer to 2N5086 for graphs.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage ($I_C = 2.0 \text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	32	—	Vdc
Emitter-Base Breakdown Voltage ($I_E = 1.0 \text{ mA}$, $I_C = 0$)	$V_{(BR)EBO}$	5.0	—	Vdc
Collector Cutoff Current ($V_{CE} = 32 \text{ Vdc}$) ($V_{CE} = 32 \text{ Vdc}$, $T_A = 150^\circ\text{C}$)	I_{CES}	—	20 20	nA μA
ON CHARACTERISTICS				
DC Current Gain ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$)	h_{FE}	20 30 40 100	— — — —	—
($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$)		120 140 250 380	220 310 460 630	
($I_C = 50 \text{ mA}$, $V_{CE} = 1.0 \text{ Vdc}$)		60 80 100 100	— — — —	
AC Current Gain ($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$, $f = 1.0 \text{ kHz}$)	h_{fe}	125 175 250 350	250 350 500 700	—
Collector-Emitter Saturation Voltage ($I_C = 50 \text{ mA}$, $I_B = 1.25 \text{ mA}$) ($I_C = 10 \text{ mA}$, $I_B = 0.25 \text{ mA}$)	$V_{CE(sat)}$	— —	0.55 0.25	Vdc
Base-Emitter Saturation Voltage ($I_C = 50 \text{ mA}$, $I_B = 1.25 \text{ mA}$) ($I_C = 10 \text{ mA}$, $I_B = 0.25 \text{ mA}$)	$V_{BE(sat)}$	0.68 0.6	1.05 0.85	Vdc
Base-Emitter On Voltage ($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$)	$-V_{BE(on)}$	0.6	0.75	Vdc

T-27-01

ELECTRICAL CHARACTERISTICS (continued) ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
SMALL SIGNAL CHARACTERISTICS				
Output Capacitance ($V_{CE} = 10\text{ Vdc}$, $I_C = 0$, $f = 1.0\text{ MHz}$)	C_{obo}	—	6.0	pF
Noise Figure ($I_C = 0.2\text{ mAdc}$, $V_{CE} = 5.0\text{ Vdc}$, $R_S = 2.0\text{ k}\Omega$, $f = 1.0\text{ kHz}$, $BW = 200\text{ Hz}$)	NF	—	6.0	dB
SWITCHING CHARACTERISTICS				
Turn-On Time ($I_C = 10\text{ mAdc}$, $I_{B1} = 1.0\text{ mAdc}$)	t_{on}	—	150	ns
Turn-Off Time ($I_{B2} = 1.0\text{ mAdc}$, $V_{BB} = 3.6\text{ Vdc}$, $R_1 = R_2 = 5.0\text{ k}\Omega$, $R_L = 990\text{ }\Omega$)	t_{off}	—	800	ns